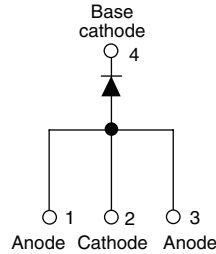


Surface Mountable Input Rectifier Diode, 8 A



D-PAK



DESCRIPTION/FEATURES

The 8EWS16SPbF rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.



The **high reverse voltage** range available allows design of input stage primary rectification with **outstanding voltage surge** capability.

Typical applications are in input rectification and these products are designed to be used with Vishay HPP switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level.

Compliant to RoHS directive 2002/95/EC.

PRODUCT SUMMARY	
V_F at 10 A	1 V
I_{FSM}	200 A
V_{RRM}	1600 V

OUTPUT CURRENT IN TYPICAL APPLICATIONS			
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 μ m) copper	1.2	1.6	A
Aluminum IMS, $R_{thCA} = 15$ °C/W	2.5	2.8	
Aluminum IMS with heatsink, $R_{thCA} = 5$ °C/W	5.5	6.5	

Note

- $T_A = 55$ °C, $T_J = 125$ °C, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Sinusoidal waveform	8	A
V_{RRM}		1600	V
I_{FSM}		200	A
V_F	8 A, $T_J = 25$ °C	1.10	V
T_J		- 40 to 150	°C

VOLTAGE RATINGS			
PART NUMBER	V_{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 °C mA
8EWS16SPbF	1600	1700	0.5

8EWS16SPbF High Voltage Series



Vishay High Power Products Surface Mountable
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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 105\text{ }^\circ\text{C}$, 180° conduction half sine wave	8	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	170	
		10 ms sine pulse, no voltage reapplied	200	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	130	A ² s
		10 ms sine pulse, no voltage reapplied	145	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1\text{ ms to }10\text{ ms}$, no voltage reapplied	1450	A ² √s

ELECTRICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum forward voltage drop	V_{FM}	8 A, $T_J = 25\text{ }^\circ\text{C}$	1.1	V
Forward slope resistance	r_t	$T_J = 150\text{ }^\circ\text{C}$	20	mΩ
Threshold voltage	$V_{F(TO)}$		0.82	V
Maximum reverse leakage current	I_{RM}	$T_J = 25\text{ }^\circ\text{C}$	0.05	mA
		$T_J = 150\text{ }^\circ\text{C}$	0.50	

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		- 40 to 150	°C
Soldering temperature	T_S		240	
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	2.5	°C/W
Typical thermal resistance, junction to ambient (PCB mount) ⁽¹⁾	R_{thJA}		62	
Approximate weight			1	g
			0.03	oz.
Marking device		Case style TO-252AA (D-PAK)	8EWS16S	

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W
For recommended footprint and soldering techniques refer to application note #AN-994



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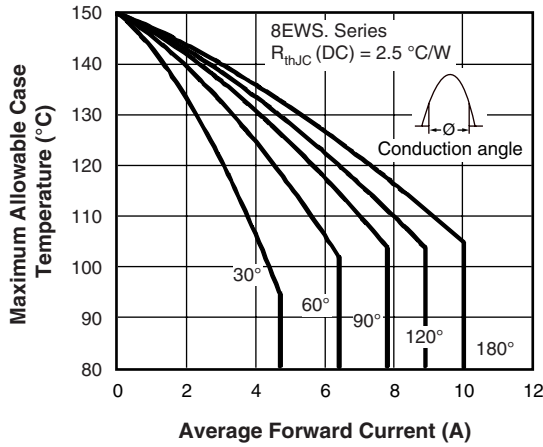


Fig. 1 - Current Rating Characteristics

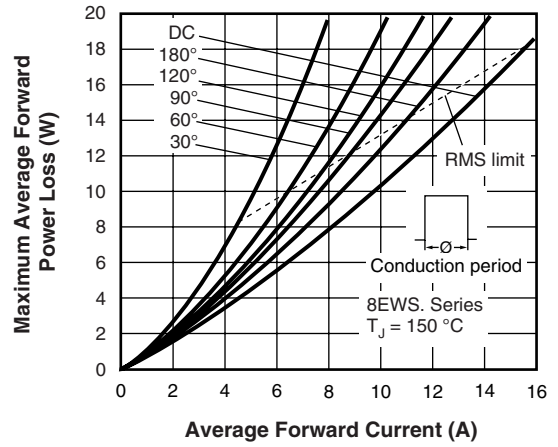


Fig. 4 - Forward Power Loss Characteristics

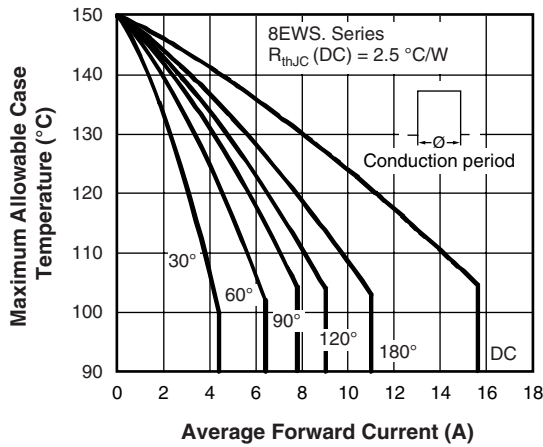


Fig. 2 - Current Rating Characteristics

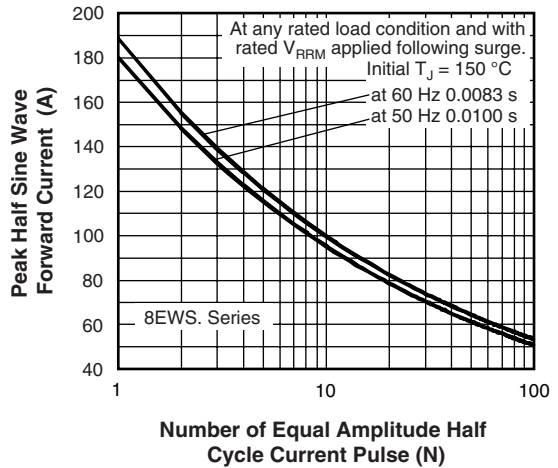


Fig. 5 - Maximum Non-Repetitive Surge Current

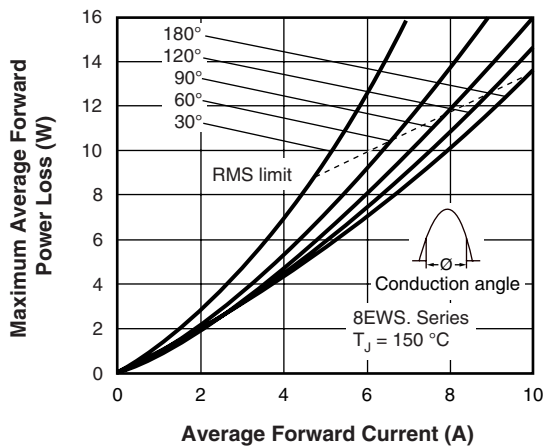


Fig. 3 - Forward Power Loss Characteristics

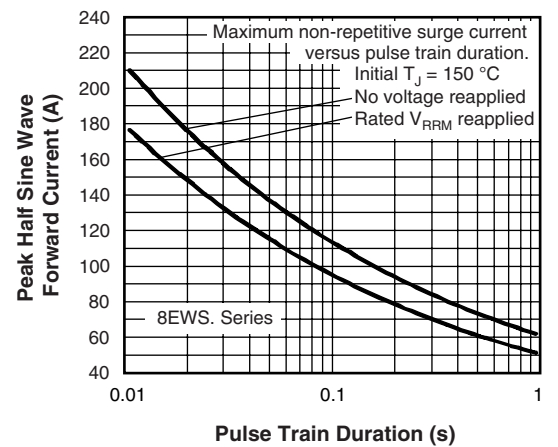


Fig. 6 - Maximum Non-Repetitive Surge Current

8EWS16SPbF High Voltage Series



Vishay High Power Products Surface Mountable
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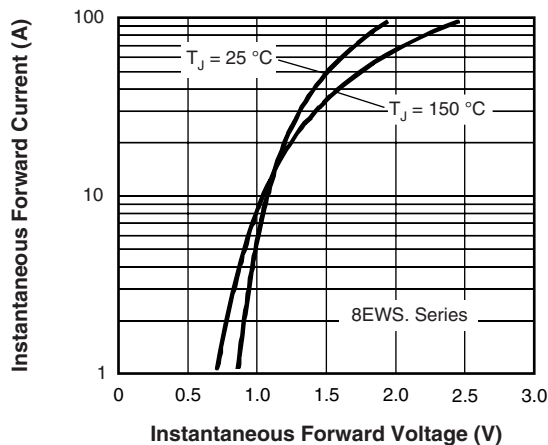


Fig. 7 - Forward Voltage Drop Characteristics

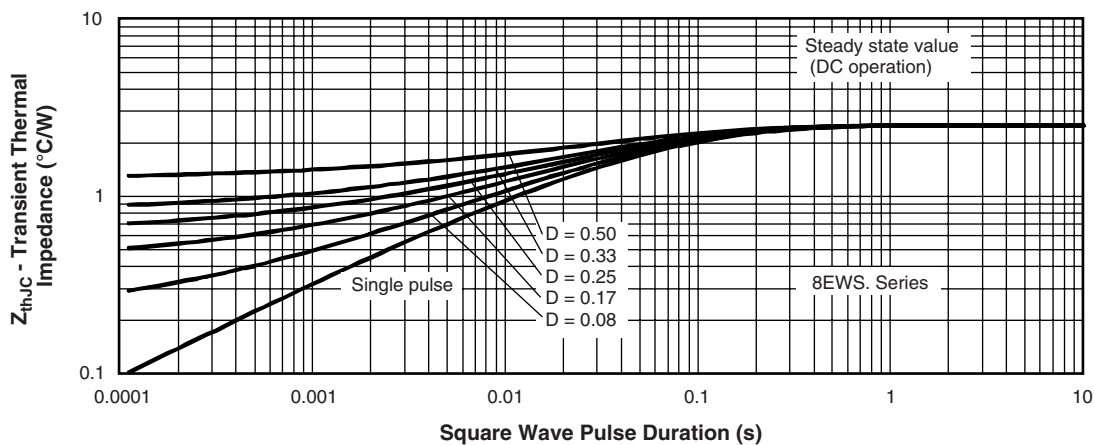


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



8EWS16SPbF High Voltage Series

Surface Mountable Vishay High Power Products
Input Rectifier Diode, 8 A

ORDERING INFORMATION TABLE

Device code	8	E	W	S	16	S	TR	PbF
	①	②	③	④	⑤	⑥	⑦	⑧

- 1** - Current rating (8 = 8 A)
- 2** - Circuit configuration:
E = Single diode
- 3** - Package:
W = D-PAK
- 4** - Type of silicon:
S = Standard recovery rectifier
- 5** - Voltage rating (16 = 1600 V)
- 6** - S = Surface mountable
- 7** -
 - TR = Tape and reel
 - TRR = Tape and reel (right oriented)
 - TRL = Tape and reel (left oriented)
- 8** - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95016
Part marking information	www.vishay.com/doc?95059
Packaging information	www.vishay.com/doc?95033



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